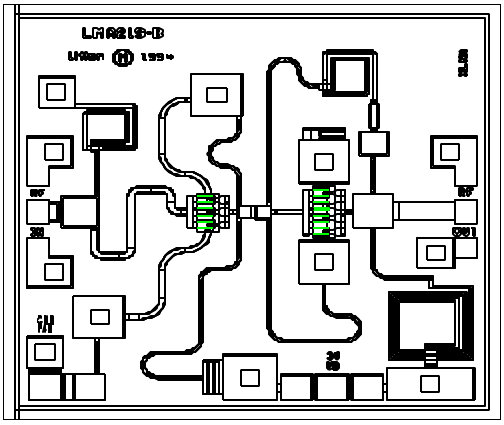
- FEATURES



  - 7 GHz to 11 GHz Frequency Band
  - 1.4 dB Noise Figure
  - 19 dB Gain
  - 14 dBm Output Power at Saturation
  - +3 V Single Bias Supply

- DESCRIPTION AND APPLICATIONS

The Filtronic Solid State LMA219B is a low noise PHEMT amplifier which operates from 7 to 11GHz. This 2-stage reactive matched amplifier produces very low figure of 1.4dB with an associated gain of 19dB. The LMA219B is designed for phased array radar applications. DC decoupled input and output RF port. Ground is provided to the circuitry through vias to the backside metallization.

- ELECTRICAL SPECIFICATIONS @ $T_{Ambient}$ = 25°C

(V_{DD} = +3.0V, Z_{IN} = Z_{OUT} = 50Ω)

Parameter	Symbol	Test Conditions	Min	Typ	Max	Units
Frequency Band	F		7		11	GHz
Small Signal Gain	S_{21}	V_{DD} = 3V, R_S = 10Ω	18	19		dB
Drain Current at Saturation	I_{DSS}	R_S = 0Ω	70	140	210	mA
Small Signal Gain Flatness	ΔS_{21}			±0.5		
Noise Figure	NF	I_{DS} = 50% I_{DSS}		1.4	3.0	dB
Power at 1-dB Compression	P-1dB		9	10		dBm
Input Return Loss	S_{11}			-12		dB
Output Return Loss	S_{22}			-10		dB
Reverse Isolation	S_{12}		-30	-40		dB

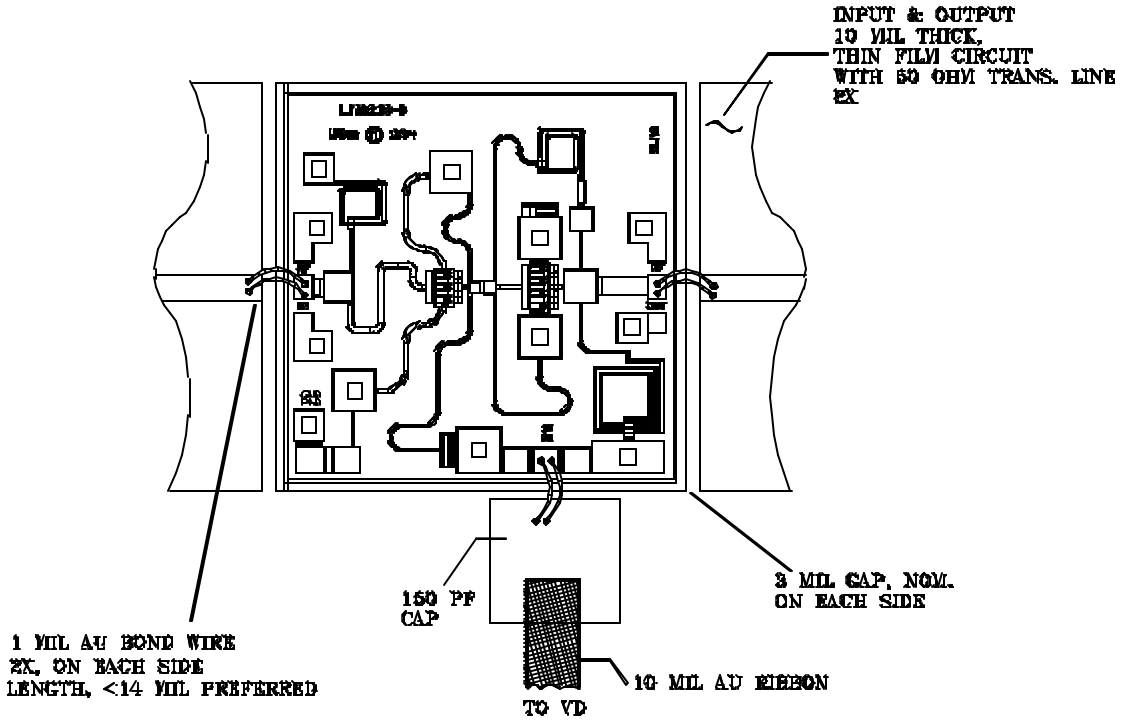
• ABSOLUTE MAXIMUM RATINGS

Parameter	Symbol	Test Conditions	Min	Max	Units
Drain Voltage	V_D	$T_{Ambient}$ = 22 ± 3 °C		4	V
Operating Current	I_{OP}	$T_{Ambient}$ = 22 ± 3 °C		210	mA
RF Input Power	P_{IN}	$T_{Ambient}$ = 22 ± 3 °C		15	dBm
Total Power Dissipation	P_{TOT}	$T_{Ambient}$ = 22 ± 3 °C		0.85	W
Channel Operating Temperature	T_{CH}	$T_{Ambient}$ = 22 ± 3 °C		150	ºC
Storage Temperature	T_{STG}	—	-65	165	ºC
Maximum Assembly Temperature (1 min. max.)	T_{MAX}	—		300	ºC

Notes:

- Operating conditions that exceed the Absolute Maximum Ratings could result in permanent damage to the device.
- Recommended Continuous Operating Limits should be observed for reliable device operation.
- Power Dissipation defined as: $P_{TOT} \equiv (P_{DC} + P_{IN}) - P_{OUT}$, where
  P_{DC}: DC Bias Power
  P_{IN}: RF Input Power
  P_{OUT}: RF Output Power
- This GaAs MMIC is susceptible to damage from Electrostatic Discharge. Proper precautions should be used when handling these devices.

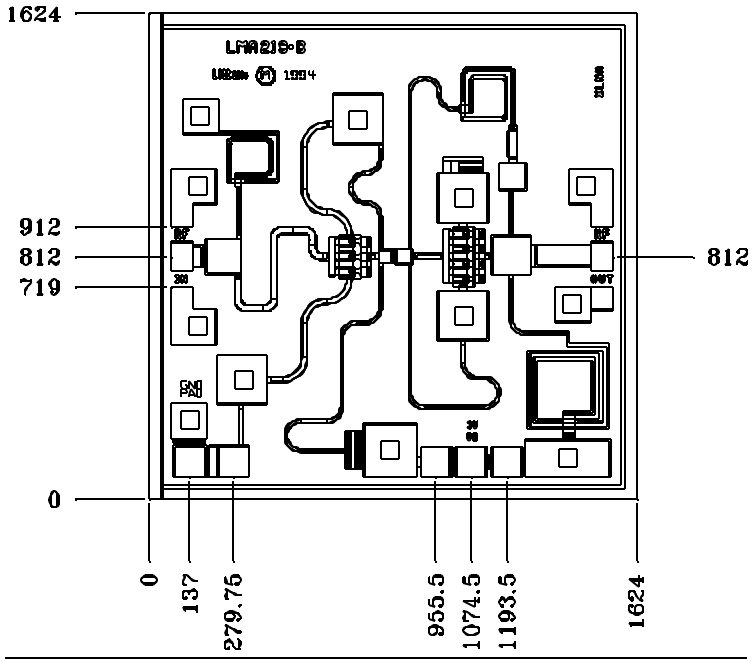
- ASSEMBLY DRAWING



Notes:

- Recommended lead bond technique is thermocompression wedge bonding with 0.001" (25µm) diameter wire. The bond tool force shall be 35-38 gram. Bonding stage temperature shall be 230-240°C, heated tool (150-160°C) is recommended. Ultrasonic bonding is not recommended.
- The recommended die attach is Ablebond silver epoxy, the stabilize bake temperature is set at 150°C for 45 minutes.
- Bond on bond or stitch bond acceptable.
- Conductor over conductor acceptable. Conductors must not short.

- MECHANICAL OUTLINE



Notes:

- All units are in microns (µm).
- All bond pads are 100 X 100 µm^2.
- Bias pad (V_{DD}) size is 100 X 121.5 µm^2.
- Unless otherwise specified.

- HANDLING PRECAUTIONS

To avoid damage to the devices care should be exercised during handling. Proper Electrostatic Discharge (ESD) precautions should be observed at all stages of storage, handling, assembly, and testing. These devices should be treated as Class 1A (0-500 V). Further information on ESD control measures can be found in MIL-STD-1686 and MIL-HDBK-263.

All information and specifications are subject to change without notice.